

DMG1013UW-7 Datasheet



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DiGi Electronics Part Number DMG1013UW-7-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number DMG1013UW-7

Description MOSFET P-CH 20V 820MA SOT323

Detailed Description P-Channel 20 V 820mA (Ta) 310mW (Ta) Surface Mo

unt SOT-323



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
DMG1013UW-7	Diodes Incorporated
Series:	Product Status:
	Active
FET Type:	Technology:
P-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
20 V	820mA (Ta)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
1.8V, 4.5V	750mOhm @ 430mA, 4.5V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
1V @ 250μA	0.622 nC @ 4.5 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±6V	59.76 pF @ 16 V
FET Feature:	Power Dissipation (Max):
	310mW (Ta)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
SOT-323	SC-70, SOT-323
Base Product Number:	
DMG1013	

Environmental & Export classification

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	





DMG1013UW

P-CHANNEL ENHANCEMENT MODE MOSFET

Features

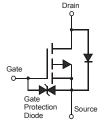
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

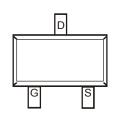
Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (approximate)









Top View

Equivalent Circuit

Top View

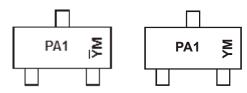
Ordering Information (Note 4)

ſ	Part Number	Case	Packaging
	DMG1013UW-7	SOT-323	3000 / Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



PA1 = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) \overline{Y} M = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or \overline{Y} = Year (ex: A = 2013) M = Month (ex: 9 = September)

Chengdu A/T Site

Shanghai A/T Site

Date Code Key

Year	2008	2	009	2010	2	2011	2012		2013	2014		2015
Code	V		W	Χ		Υ	Z		Α	В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D





Char	Symbol	Value	Unit		
Drain-Source Voltage	V_{DSS}	-20	V		
Gate-Source Voltage			V_{GSS}	±6	V
Continuous Drain Current (Note 5)	I _D	-0.82 -0.54	Α		
Pulsed Drain Current (Note 6)	I _{DM}	-6	Α		

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_{D}	0.31	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	$R_{\theta JA}$	398	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

- 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.
- 6. Repetitive rating, pulse width limited by junction temperature.

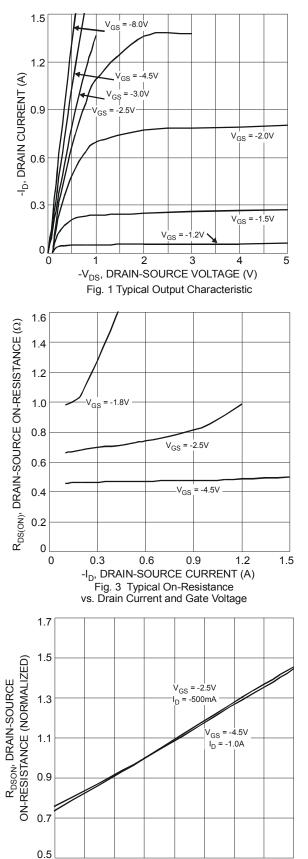
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

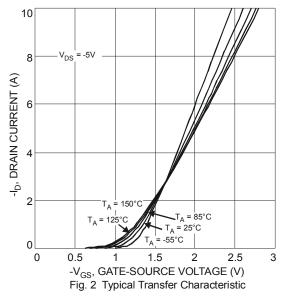
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-20	-	-	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	-	-	-100	nA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	1	-	±2.0	μΑ	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	-0.5	-	-1.0	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
			0.5	0.75		$V_{GS} = -4.5V$, $I_D = -430$ mA	
Static Drain-Source On-Resistance	R _{DS (ON)}	-	0.7	1.05	Ω	$V_{GS} = -2.5V$, $I_D = -300$ mA	
			1.0	1.5		$V_{GS} = -1.8V$, $I_D = -150mA$	
Forward Transfer Admittance	Y _{fs}	1	0.9	1	S	$V_{DS} = -10V, I_{D} = -250mA$	
Diode Forward Voltage	V_{SD}		-0.8	-1.2	V	$V_{GS} = 0V, I_S = -150mA$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	-	59.76	-	pF	101/11/	
Output Capacitance	Coss	1	12.07	ı	рF	$V_{DS} = -16V, V_{GS} = 0V,$ -f = 1.0MHz	
Reverse Transfer Capacitance	C_{rss}	-	6.36	-	pF	1 - 1.01/11/12	
Total Gate Charge	Q_g	-	622.4	-	рC	1/ 45)/)/ 40)/	
Gate-Source Charge	Qgs	-	100.3	-	рC	$V_{GS} = -4.5V, V_{DS} = -10V,$ $I_{D} = -250 \text{mA}$	
Gate-Drain Charge	Q_{gd}	-	132.2	-	рC	1D = -25011IA	
Turn-On Delay Time	t _{D(on)}	-	5.1	-	ns	101/11/	
Turn-On Rise Time	t _r	-	8.1	-	ns	$V_{DD} = -10V, V_{GS} = -4.5V,$	
Turn-Off Delay Time	$t_{D(off)}$	-	28.4	-	ns	$R_L = 47\Omega, R_G = 10\Omega,$ $I_D = -200\text{mA}$	
Turn-Off Fall Time	t _f	-	20.7	-	ns	1D200IIIA	

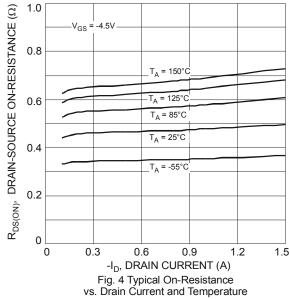
Notes:

- 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to production testing.









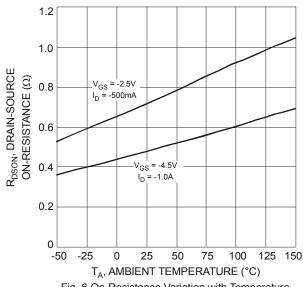


Fig. 6 On-Resistance Variation with Temperature

-50 -25

0

25

50

T_A, AMBIENT TEMPERATURE (°C)

Fig. 5 On-Resistance Variation with Temperature

75

100

125

DECDES.

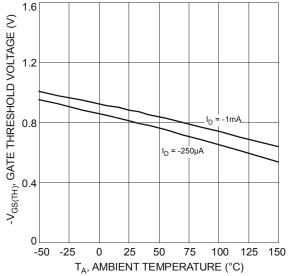
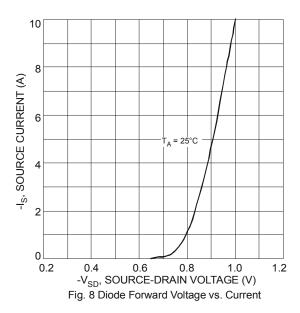
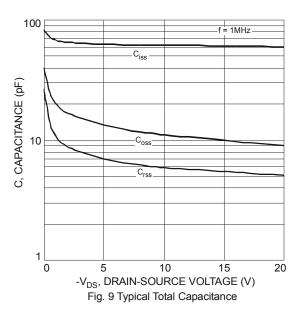


Fig. 7 Gate Threshold Variation vs. Ambient Temperature





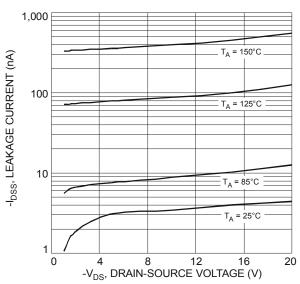


Fig. 10 Typical Leakage Current vs. Drain-Source Voltage

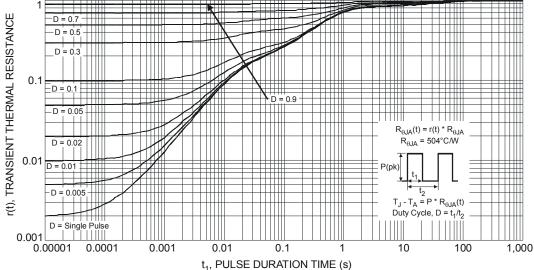
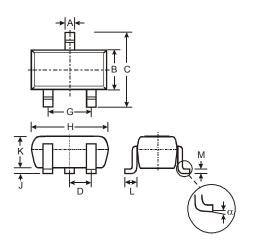


Fig. 11 Transient Thermal Response



Package Outline Dimensions

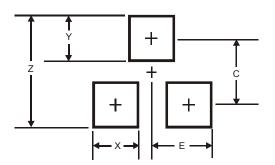
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT-323							
Dim	Min	Max	Тур				
Α	0.25	0.40	0.30				
В	1.15	1.35	1.30				
C	2.00	2.20	2.10				
D	-	-	0.65				
G	1.20	1.40	1.30				
Н	1.80	2.20	2.15				
J	0.0	0.10	0.05				
K	0.90	1.00	0.95				
٦	0.25	0.40	0.30				
М	0.10	0.18	0.11				
α	0°	8°	-				
All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Υ	0.9
С	1.9
E	1.0





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